



Order

Now



Support & 22 Community



TS3L110

SCDS176B-SEPTEMBER 2004-REVISED OCTOBER 2019

TS3L110 Quad SPDT High-Bandwidth 10/100 Base-T LAN Switch **Differential 8-Channel to 4-Channel Multiplexer/Demultiplexer**

Features 1

- Wide bandwidth (BW = 500 MHz typical)
- Low crosstalk ($X_{TALK} = -30 \text{ dB typical}$)
- Bidirectional data flow with near-zero propagation delay
- Low and flat ON-state resistance $(r_{on} = 4 \Omega \text{ typical}, r_{on(flat)} = 1 \Omega)$
- Switching on Data I/O Ports (0 to 5 V)
- V_{CC} Operating range from 3 V to 3.6 V
- Ioff Supports partial power-down-mode operation
- Data and control inputs have undershoot clamp diodes
- Latch-up performance exceeds 100 mA Per JESD 78, class II
- ESD Performance tested per JESD 22
 - 2000-V Human-body model (A114-B, class II)
 - 1000-V Charged-device model (C101)
- Suitable for both 10 Base-T and 100 Base-T signaling

Applications 2

10 and 100 Base-T signal switching

Description 3

The TS3L110 local area network (LAN) switch is a 4bit 1-of-2 multiplexer/demultiplexer with a single switch-enable (E) input. When E is low, the switch is enabled, and the I port is connected to the Y port. When \overline{E} is high, the switch is disabled, and the highimpedance state exists between the I and Y ports. The select (S) input controls the data path of the multiplexer/demultiplexer.

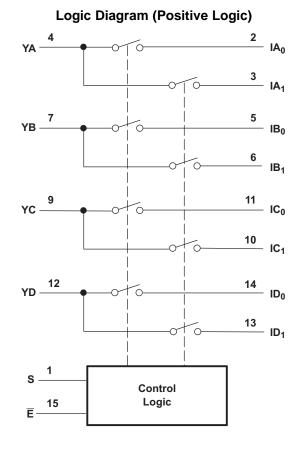
The TS3L110 device can be used to replace mechanical relays in LAN applications. This device has low and flat ON-state resistance (ron), wide bandwidth, and low crosstalk, making it suitable for 10/100 Base-T and various other LAN applications. The TS3L110 device can be used to route signals from a 10/100 Base-T Ethernet transceiver to the RJ-45 LAN connectors in laptops or in docking stations. This device is designed for low channel-to-channel skew and low crosstalk.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} feature ensures that damaging current does not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, \overline{E} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

| Device Information ⁽¹⁾ | | | | | | |
|-----------------------------------|----------------|-------------------|--|--|--|--|
| PART NUMBER | PACKAGE | BODY SIZE (NOM) | | | | |
| | SOIC (D) 16 | 9.90 mm x 3.91 mm | | | | |
| | SSOP (DBQ) 16 | 4.90 mm x 3.90 mm | | | | |
| TS3L110 | TVSOP (DGV) 16 | 3.60 mm x 4.40 mm | | | | |
| | TSSOP (PW) 16 | 5.00 mm x 4.40 mm | | | | |
| | VQFN (RGV) 16 | 4.00 mm x 4.00 mm | | | | |

(1) For all available packages, see the orderable addendum at the end of the data sheet.



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

TS3L110

Table of Contents

| 1 | Feat | tures 1 |
|---|------|------------------------------------|
| 2 | Арр | lications 1 |
| 3 | Des | cription 1 |
| 4 | Rev | ision History 2 |
| 5 | Pin | Configuration and Functions 3 |
| 6 | Spe | cifications 4 |
| | 6.1 | Absolute Maximum Ratings 4 |
| | 6.2 | ESD Ratings 4 |
| | 6.3 | Recommended Operating Conditions 4 |
| | 6.4 | Thermal Information 5 |
| | 6.5 | Electrical Characteristics 5 |
| | 6.6 | Switching Characteristics6 |
| | 6.7 | Dynamic Characteristics 6 |
| | 6.8 | Typical Characteristics 7 |
| 7 | Para | ameter Measurement Information |
| 8 | Deta | ailed Description 13 |
| | 8.1 | Overview 13 |
| | | |

| | 8.2 | Functional Block Diagram | 13 |
|----|------|---|----|
| | 8.3 | Feature Description | 13 |
| | 8.4 | Device Functional Modes | 13 |
| 9 | App | lication and Implementation | 14 |
| | 9.1 | Application Information | 14 |
| | 9.2 | Typical Application | 14 |
| 10 | Pow | er Supply Recommendations | 15 |
| 11 | Lay | out | 16 |
| | 11.1 | Layout Guidelines | 16 |
| | 11.2 | Layout Example | 17 |
| 12 | Dev | ice and Documentation Support | 18 |
| | 12.1 | Receiving Notification of Documentation Updates | 18 |
| | 12.2 | Community Resources | 18 |
| | 12.3 | Trademarks | 18 |
| | 12.4 | Electrostatic Discharge Caution | 18 |
| | 12.5 | Glossary | 18 |
| 13 | | hanical, Packaging, and Orderable | |
| | Info | mation | 18 |
| | | | |

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Cł | hanges from Revision A (May 2019) to Revision B | Page |
|----|--|------|
| • | Change pin 10 to IC ₁ , pin 11 to IC ₀ , pin 13 to ID ₁ , and pin 14 to ID ₀ in the <i>Pin Configuration and Functions</i> | 3 |

Changes from Original (September 2004) to Revision A

Added Device Information table, ESD Ratings table, Thermal Information table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section..... 1

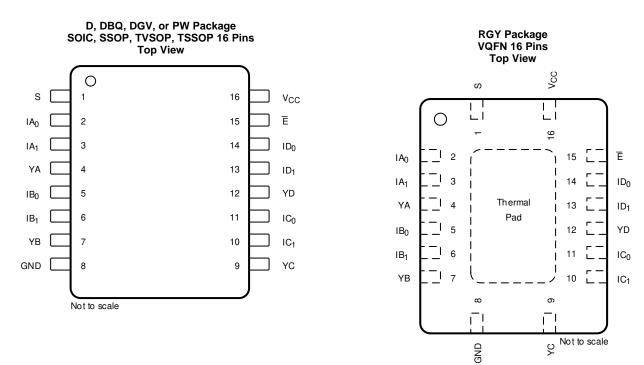
www.ti.com

XAS STRUMENTS

Page



5 Pin Configuration and Functions



Pin Functions

| | PIN | | | | |
|-----------------|-----|---|--|--|--|
| NAME NO. | | DESCRIPTION | | | |
| S | 1 | Select input | | | |
| IA ₀ | 2 | Data I/Os | | | |
| IA ₁ | 3 | Data I/Os | | | |
| YA | 4 | Data I/Os | | | |
| IB ₀ | 5 | Data I/Os | | | |
| IB ₁ | 6 | Data I/Os | | | |
| YB | 7 | Data I/Os | | | |
| GND | 8 | Ground (0 V) reference | | | |
| YC | 9 | Data I/Os | | | |
| IC ₁ | 10 | Data I/Os | | | |
| IC ₀ | 11 | Data I/Os | | | |
| YD | 12 | Data I/Os | | | |
| ID ₁ | 13 | Data I/Os | | | |
| ID ₀ | 14 | Data I/Os | | | |
| Ē | 15 | Enable input | | | |
| V _{CC} | 16 | Positive power supply. This pin is the most positive power-supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1 μ F to 10 μ F between VDD and GND. | | | |

6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|-------------------|---|----------------------------|------|------|------|
| V _{CC} | Supply voltage range | | -0.5 | 4.6 | V |
| V _{IN} | Control input voltage range ⁽²⁾⁽³⁾ | | -0.5 | 7 | V |
| V _{I/O} | Switch I/O voltage range ⁽²⁾⁽³⁾⁽⁴⁾ | | -0.5 | 7 | V |
| I _{IK} | Control input clamp current | V _{IN} < 0 | | -50 | mA |
| I _{I/OK} | I/O port clamp current | V _{I/O} < 0 | | -50 | mA |
| I _{I/O} | ON-state switch current ⁽⁵⁾ | | | ±128 | mA |
| | Continuous current through V _{CC} or GND | | | ±100 | mA |
| | | D package ⁽⁶⁾ | | 73 | |
| | | DBQ package ⁽⁶⁾ | | 90 | |
| θ_{JA} | Package thermal impedance | DGV package ⁽⁶⁾ | | 120 | °C/W |
| | | PW package ⁽⁶⁾ | | 108 | |
| | | RGY package ⁽⁷⁾ | | 39 | |
| T _{stg} | Storage temperature range | | -65 | 150 | °C |

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to ground, unless otherwise specified.

(3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(4) V_I and V_O are used to denote specific conditions for $V_{I/O}$.

(5) I_{I} and I_{O} are used to denote specific conditions for $I_{I/O}$.

(6) The package thermal impedance is calculated in accordance with JESD 51-7.

(7) The package thermal impedance is calculated in accordance with JESD 51-5.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|-------------|---|--|-------|------|
| | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | | |
| $V_{(ESD)}$ | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 or ANSI/ESDA/JEDEC JS-002 ⁽²⁾ | ±1000 | V |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. e.

6.3 Recommended Operating Conditions⁽¹⁾

| | | MIN | MAX | UNIT |
|------------------|---|-----|-----|------|
| V _{CC} | Supply voltage | 3 | 3.6 | V |
| V _{IH} | High-level control input voltage (E, S) | 2 | 5.5 | V |
| VIL | Low-level control input voltage (E, S) | 0 | 0.8 | V |
| V _{I/O} | Input/output voltage | 0 | 5.5 | V |
| T _A | Operating free-air temperature | -40 | 85 | °C |

 All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

www.ti.com

6.4 Thermal Information

| | | | TS3L110 | | | | |
|-------------------------------|--|----------|------------|-------------|------------|------------|------|
| THERMAL METRIC ⁽¹⁾ | | D (SOIC) | DBQ (SSOP) | DGV (TVSOP) | PW (TSSOP) | RGV (VQFN) | UNIT |
| | | 16 PINS | 16 PINS | 16 PINS | 16 PINS | 16 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 92.0 | 114.5 | 139.3 | 111.5 | 50.8 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 52.3 | 60.5 | 57.4 | 42.0 | 48.1 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 50.3 | 58.2 | 73.7 | 57.8 | 26.7 | °C/W |
| ψ_{JT} | Junction-to-top characterization parameter | 17.3 | 15.3 | 7.2 | 4.2 | 2.1 | °C/W |
| ΨJB | Junction-to-board characterization parameter | 50.0 | 57.6 | 73.0 | 57.2 | 26.5 | °C/W |
| $R_{\thetaJC(bot)}$ | Junction-to-case (bottom) thermal resistance | - | - | - | - | 10.7 | °C/W |

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

Electrical Characteristics⁽¹⁾ 6.5

over recommended operating free-air temperature range, V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted)

| PARAMETER | | | TEST CONDITIC | NS | MIN | TYP ⁽²⁾ | MAX | UNIT |
|--------------------------------------|----------------|------------------------|--|---|-----|--------------------|------|------|
| V _{IK} | Ē, S | $V_{CC} = 3.6 V,$ | I _{IN} = -18 mA | | | | -1.8 | V |
| I _{IH} | Ē, S | $V_{CC} = 3.6 V,$ | V _{IN} = 5.5 V | | | | ±1 | μA |
| IIL | Ē, S | $V_{CC} = 3.6 V,$ | $V_{IN} = GND$ | | | | ±1 | μA |
| I _{off} | | $V_{CC} = 0,$ | $V_{O} = 0$ to 5.5 V, | $V_{I} = 0$ | | | 1 | μA |
| I _{CC} | | $V_{CC} = 3.6 V,$ | $I_{I/O} = 0,$ | Switch ON or OFF | | 0.7 | 1.5 | mA |
| Cin | Ē, S | f = 1 MHz, | $V_{IN} = 0$ | | | 2.5 | 3.5 | pF |
| <u> </u> | I port | $V_{I} = 0,$ | f = 1 MHz, Outputs open, | Switch OFF | | 3.5 | 5 | - |
| C _{io(OFF)} | Y port | $V_{I} = 0,$ | f = 1 MHz, Outputs open, | Switch OFF | | 5.5 | 7 | pF |
| C _{io(ON)} | I or Y port | $V_{I} = 0,$ | f = 1 MHz, Outputs open, | Switch ON | | 10.5 | 13 | pF |
| r _{on} | | $V_{CC} = 3 V,$ | $1.25 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{CC}},$ | $I_{O} = -10$ mA to -30 mA | | 4 | 8 | Ω |
| r _{on(flat)} ⁽³⁾ | | V _{CC} = 3 V, | V_I = 1.25 V and V_{CC} , | $I_{O} = -10 \text{ mA to } -30 \text{ mA}$ | | 1 | | Ω |
| $\Delta r_{on}^{(4)}$ | | V _{CC} = 3 V, | $1.25 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{CC}},$ | $I_{O} = -10 \text{ mA to } -30 \text{ mA}$ | | 0.9 | 2 | Ω |

 $\begin{array}{ll} (1) & V_{I}, \, V_{O}, \, I_{I}, \, \text{and} \, I_{O} \, \text{refer to I/O pins.} \, V_{IN} \, \text{refers to the control inputs.} \\ (2) & \text{All typical values are at} \, V_{CC} = 3.3 \, V \, (\text{unless otherwise noted}), \, T_{A} = 25^{\circ}\text{C}. \\ (3) & r_{on(flat)} \, \text{is the difference of } r_{on} \, \text{in a given channel at specified voltages.} \\ (4) & \Delta r_{on} \, \text{is the difference of } r_{on} \, \text{in a given device.} \end{array}$



www.ti.com

6.6 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V, R_L = 200 $\Omega,$ C_L = 10 pF (unless otherwise noted) (see Figure 5 and Figure 6)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | MIN | TYP ⁽¹⁾ | МАХ | UNIT |
|-------------------------------------|-----------------|----------------|-----|--------------------|-----|------|
| t _{pd} ⁽²⁾ | l or Y | Y or I | | 0.25 | | ns |
| t _{PZH} , t _{PZL} | E or S | l or Y | 0.5 | | 7 | ns |
| t _{PHZ} , t _{PLZ} | E or S | l or Y | 0.5 | | 5 | ns |
| $t_{sk(p)}^{(3)}$ | l or Y | Y or I | | 0.1 | 0.2 | ns |

All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C.
 The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).

(3) Skew between opposite transitions of the same output |t_{PHL} - t_{PLH}|. This parameter is not production tested.

Dynamic Characteristics 6.7

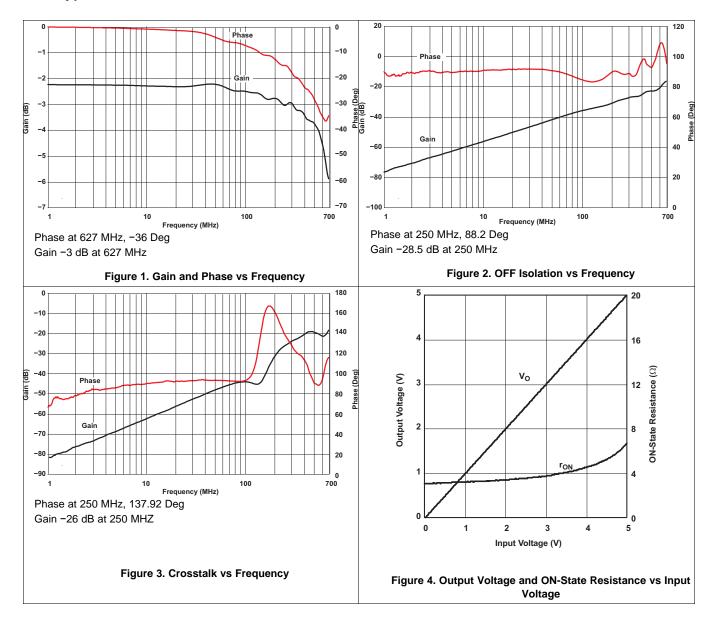
over recommended operating free-air temperature range, V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | | | |
|-------------------|----------------------|-----------------|--------------|--|-----|-----|
| X _{TALK} | $R_L = 100 \Omega$, | f = 250 MHz, | See Figure 7 | | -26 | dB |
| O _{IRR} | $R_L = 100 \Omega$, | f = 250 MHz, | See Figure 8 | | -28 | dB |
| BW | $R_L = 100 \Omega$, | | See Figure 6 | | 500 | MHz |

(1) All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C.

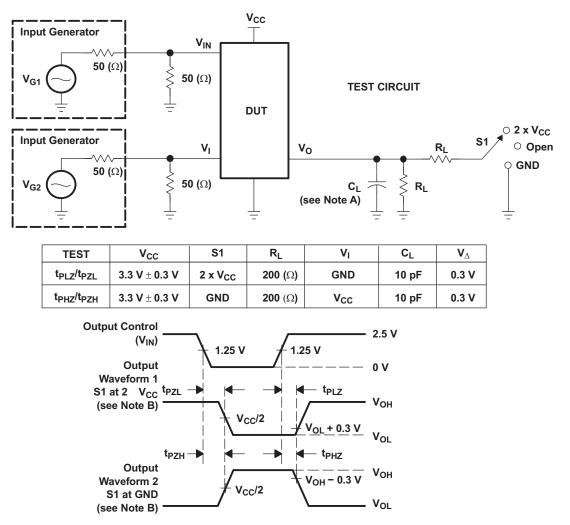


6.8 Typical Characteristics





7 Parameter Measurement Information

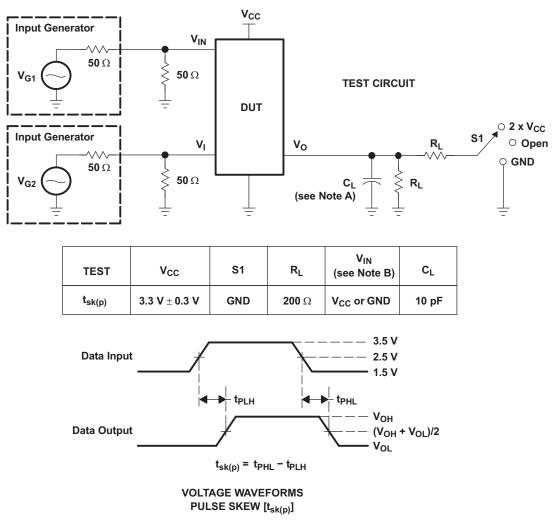


VOLTAGE WAVEFORMS ENABLE AND DISABLE TIMES

- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z₀ = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- $F. \quad t_{PLZ} \text{ and } t_{PHH} \text{ are the same as } t_{en}.$

Figure 5. Test Circuit and Voltage Waveforms





Parameter Measurement Information (continued)

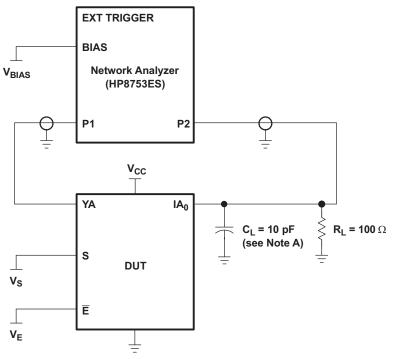
- A. C_L includes probe and jig capacitance.
- B. Switch is ON during the measurement of $t_{sk(p)}$, that is, voltage at E = 0 and S = V_{CC} or GND.

Figure 6. Test Circuit and Voltage Waveforms

TEXAS INSTRUMENTS

www.ti.com





A. C_L includes probe and jig capacitance.

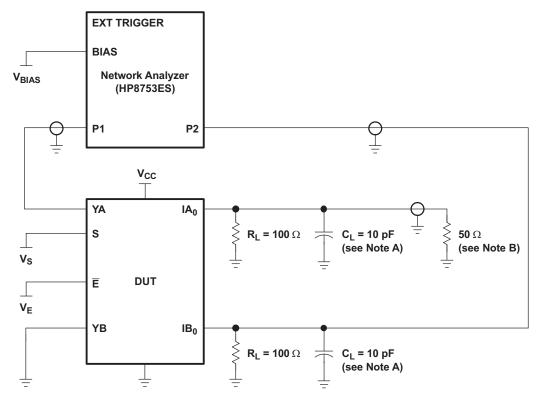


Frequency response is measured at the output of the ON channel. For example, when $V_S = 0$, $V_E = 0$, and YA is the input, the output is measured at IA₀. All unused analog I/O ports are left open.

HP8753ES Setup

- Average = 4
- RBW = 3 kHz
- V_{BIAS} = 0.35 V
- ST = 2 s
- P1 = 0 dBM

SCDS176B-SEPTEMBER 2004-REVISED OCTOBER 2019



Parameter Measurement Information (continued)

A. C_L includes probe and jig capacitance.

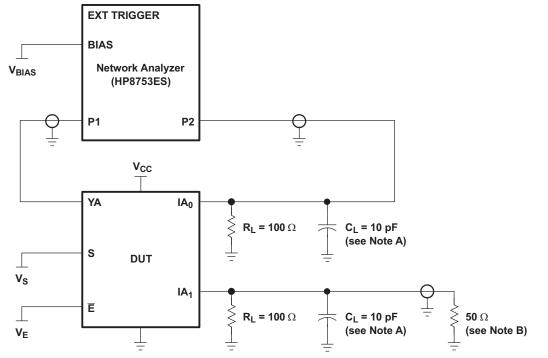
B. A 50- Ω termination resistor is needed to match the loading of the network analyzer

Figure 8. Test Circuit for Crosstalk (X_{TALK})

Crosstalk is measured at the output of the nonadjacent ON channel. For example, when $V_S = 0$, $V_E = 0$, and YA is the input, the output is measured at IB₀. All unused analog input (Y) ports are connected to GND, and output (I) ports are connected to GND through 50- Ω pulldown resistors.

HP8753ES Setup

- Average = 4
- RBW = 3 kHz
- V_{BIAS} = 0.35 V
- ST = 2 s
- P1 = 0 dBM



Parameter Measurement Information (continued)

A. C_L includes probe and jig capacitance.

B. A 50- Ω termination resistor is needed to match the loading of the network analyzer

Figure 9. Test Circuit for OFF Isolation (O_{IRR})

OFF isolation is measured at the output of the OFF channel. For example, when $V_S = V_{CC}$, $V_E = 0$, and YA is the input, the output is measured at IA₀. All unused analog input (Y) ports are left open, and output (I) ports are connected to GND through 50- Ω pulldown resistors.

HP8753FS Setup

- Average = 4
- RBW = 3 kHz
- V_{BIAS} = 0.35 V
- ST = 2 s
- P1 = 0 dBM

www.ti.com

NSTRUMENTS

ÈXAS

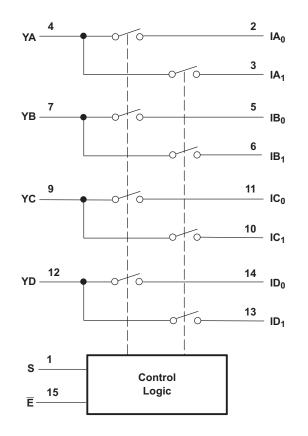


8 Detailed Description

8.1 Overview

The TI TS3L110 LAN switch is a 4-bit 1-of-2 multiplexer/demultiplexer with a single switch-enable (E) input. When E is low, the switch is enabled, and the I port is connected to the Y port. When E is high, the switch is disabled, and the high-impedance state exists between the I and Y ports. The select (S) input controls the data path of the multiplexer/demultiplexer.

8.2 Functional Block Diagram



8.3 Feature Description

Ioff supports Partial-Power-Down Mode Operation.

The TS3L110 device ensures the signal path is high impedance state when $V_{CC} = 0 V$.

8.4 Device Functional Modes

The TS3L110 supports a power down mode which reduces the current consumption of the device and places all the signal paths in a high impedance state. To place the TS3L100 in power down mode, set the \overline{E} pin with a logic high voltage as seen in Table 1.

| INPUTS | | INPUT/OUTPUT | FUNCTION | | | |
|--------|---|-----------------|-------------|--|--|--|
| Ē | S | YX | FONCTION | | | |
| L | L | IX ₀ | $YX = IX_0$ | | | |
| L | Н | IX ₁ | $YX = IX_1$ | | | |
| Н | Х | Z | Disconnect | | | |

Table 1. Function Table



9 Application and Implementation

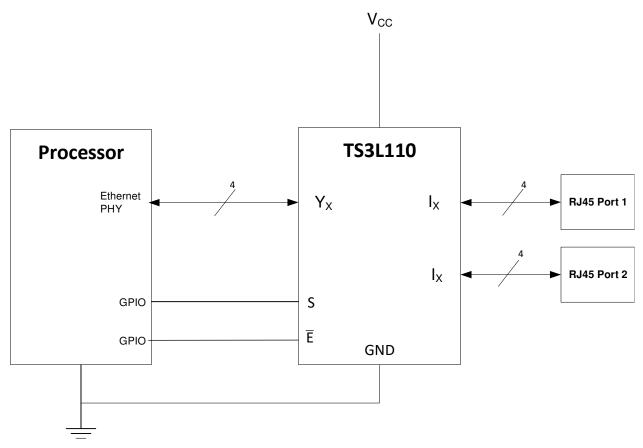
NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

There are many Local Area Network (LAN) applications in which the ethernet hubs or controllers have a limited number of I/Os or need to route signals from a single ethernet PHY to multiple ethernet jacks. The TS3L110 solution can effectively expand the limited I/Os by switching between multiple Ethernet jacks to interface them to a single Ethernet PHY.

9.2 Typical Application





9.2.1 Design Requirements

Ensure that all of the signals passing through the switch are within the recommended operating ranges. To ensure proper performance, see Recommended Operating Conditions.

9.2.2 Detailed Design Procedure

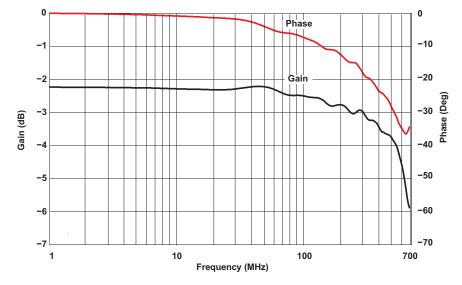
The TS3L110 can be properly operated without any external components. TI recommends that the digital control pins S and \overline{E} be pulled up to VCC or down to GND to avoid undesired switch positions that could result from the floating pin. Connect the exposed thermal pad to ground.



www.ti.com

Typical Application (continued)

9.2.3 Application Curves



Phase at 627 MHz, -36 Deg

Gain -3 dB at 627 MHz

Figure 11. Gain and Phase vs Frequency

10 Power Supply Recommendations

Power to the device is supplied through the VCC pins. TI recommends placing a bypass capacitor as close to the supply pin (VCC) as possible to help smooth out lower frequency noise to provide better load regulation across the frequency spectrum.



www.ti.com

11 Layout

11.1 Layout Guidelines

- TI recommends keeping the high-speed signals as short as possible.
- Each via introduces discontinuities in the transmission line of the signal and increases the chance of picking up interference from the other layers of the board. Be careful when designing test points on twisted pair lines; through-hole pins are not recommended.
- When it becomes necessary to turn 90°, use two 45° turns or an arc instead of making a single 90° turn. This reduces reflections on the signal traces by minimizing impedance discontinuities.
- Do not route traces under or near crystals, oscillators, clock signal generators, switching regulators, mounting holes, magnetic devices or ICs that use or duplicate clock signals.
- Avoid stubs on the high-speed signals because they cause signal reflections. If a stub is unavoidable, then the stub must be less than 200 mm.
- Route all high-speed signal traces over continuous GND planes, with no interruptions. Avoid crossing over anti-etch, commonly found with plane splits.
- Due to high-frequency signals, a printed-circuit board with at least four layers is recommended; two signal layers separated by a ground and power layer as shown in Figure 12.
- The majority of signal traces must run on a single layer, preferably Signal 1. Immediately next to this layer should be the GND plane, which is solid with no cuts. Avoid running signal traces across a split in the ground or power plane. When running across split planes is unavoidable, sufficient decoupling must be used. Minimizing the number of signal vias reduces EMI by reducing inductance at high frequencies.

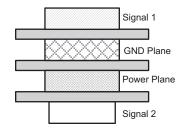
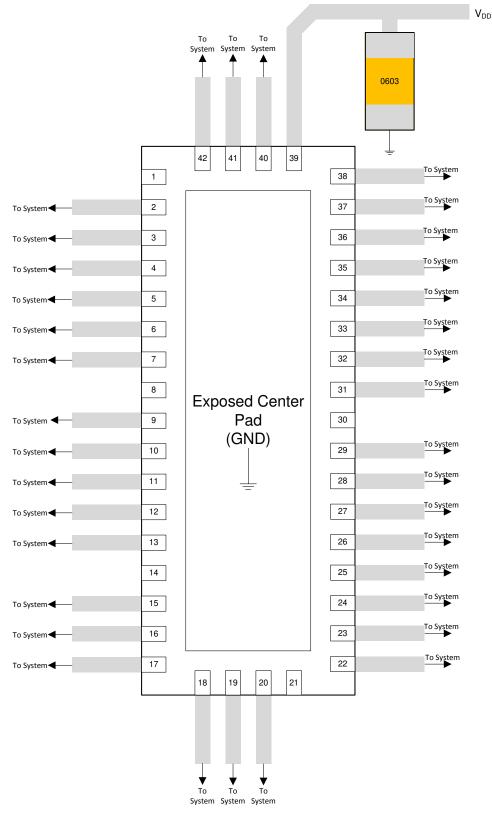


Figure 12. Four-Layer Board Stackup



11.2 Layout Example







www.ti.com

12 Device and Documentation Support

12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.2 Community Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.3 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|-------------------------------|---------------------|--------------|-------------------------|---------|
| | (.) | | Ū | | | (=) | (6) | (0) | | () | |
| TS3L110D | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TS3L110 | Samples |
| TS3L110DBQR | ACTIVE | SSOP | DBQ | 16 | 2500 | RoHS & Green | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TK110 | Samples |
| TS3L110DE4 | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TS3L110 | Samples |
| TS3L110DG4 | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TS3L110 | Samples |
| TS3L110DGVR | ACTIVE | TVSOP | DGV | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TK110 | Samples |
| TS3L110DR | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TS3L110 | Samples |
| TS3L110PW | OBSOLETE | TSSOP | PW | 16 | | TBD | Call TI | Call TI | -40 to 85 | TK110 | |
| TS3L110PWR | ACTIVE | TSSOP | PW | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TK110 | Samples |
| TS3L110RGYR | ACTIVE | VQFN | RGY | 16 | 3000 | RoHS & Green | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TK110 | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



PACKAGE OPTION ADDENDUM

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| All dimensions are nomina Device | | Package Drawing | | SPQ | Reel Diameter | Reel Width | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---|-------|--------------------|----|------|------------------|---------------|------------|------------|------------|------------|-----------|------------------|
| | | 5 | | | (mm) | W1 (mm) | · · / | l` ´ | , , | , , | | |
| TS3L110DBQR | SSOP | DBQ | 16 | 2500 | 330.0 | 12.5 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TS3L110DGVR | TVSOP | DGV | 16 | 2000 | 330.0 | 12.4 | 6.8 | 4.0 | 1.6 | 8.0 | 12.0 | Q1 |
| TS3L110DR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| TS3L110PWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| TS3L110RGYR | VQFN | RGY | 16 | 3000 | 330.0 | 12.4 | 3.8 | 4.3 | 1.5 | 8.0 | 12.0 | Q1 |



PACKAGE MATERIALS INFORMATION

14-Dec-2024



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TS3L110DBQR | SSOP | DBQ | 16 | 2500 | 353.0 | 353.0 | 32.0 |
| TS3L110DGVR | TVSOP | DGV | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| TS3L110DR | SOIC | D | 16 | 2500 | 340.5 | 336.1 | 32.0 |
| TS3L110PWR | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| TS3L110RGYR | VQFN | RGY | 16 | 3000 | 356.0 | 356.0 | 35.0 |

TEXAS INSTRUMENTS

www.ti.com

14-Dec-2024

TUBE



- B - Alignment groove width

*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | Τ (μm) | B (mm) |
|------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| TS3L110D | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| TS3L110DE4 | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| TS3L110DG4 | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



DBQ0016A



PACKAGE OUTLINE

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 inch, per side.
- This dimension does not include interlead flash.
 Reference JEDEC registration MO-137, variation AB.



DBQ0016A

EXAMPLE BOARD LAYOUT

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DBQ0016A

EXAMPLE STENCIL DESIGN

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA



- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Æ Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated.
- The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: All linear dimensions are in millimeters





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.

D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.

- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025, Texas Instruments Incorporated